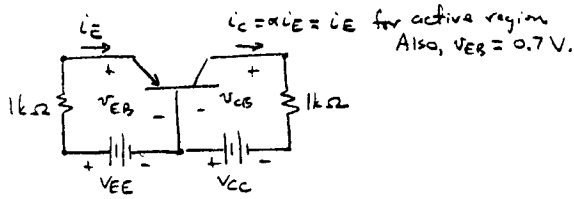


7.3



(a) By KVL, $v_{BE} - V_{EE} + 1k i_E = 0$
 $v_{BE} + 1k i_E = V_{EE}$

For $i_E = 5.3mA$, $V_{EE} = v_{BE} + 1k i_E = 0.7 + 1k(5.3m) = \underline{6V}$

(b) By KVL, $v_{CE} = 1k i_C - V_{CC}$
 $V_{CC} = 1k i_C - v_{CE} = 1k i_E - v_{CE}$

For $i_E = 5.3mA$, $v_{CE} = -3.7V$, then

$V_{CC} = 1k(5.3m) - (-3.7) = \underline{9V}$

(c) The transistor is in the active region when $i_E > 0A$ and $v_{CE} < 0.5V$.

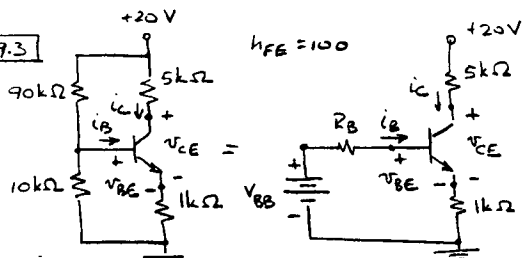
Thus,

$v_{CE} = 1k i_C - V_{CC} < 0.5$
 $1k i_C - 0.5 < V_{CC} \Rightarrow V_{CC} > 1k i_C - 0.5 = 1k i_E - 0.5$

For $i_E = 5.3mA$, $V_{CC} > 1k(5.3m) - 0.5 = 4.8V$

Hence, the minimum value for V_{CC} is 4.8V.

7.9.3



$R_B = 10k / 90k = \frac{(10k)(90k)}{10k + 90k} = \frac{900k^2}{100k} = 9k\Omega$

$V_{BB} = \frac{10k}{10k + 90k} (20) = 2V$

For active region, $v_{BE} = 0.7V$, $i_C = h_{FE} i_B = 100 i_B$

By KVL,

$V_{BB} = R_B i_B + v_{BE} + 1k(i_B + i_C)$
 $2 = 9k i_B + 0.7 + 1k(i_B + 100i_B)$

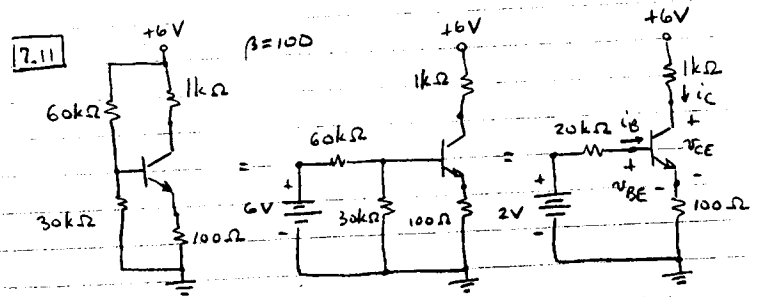
$1.3 = 110k i_B$
 $i_B = \frac{1.3}{110k} = 11.8\mu A$

$I_C = h_{FE} i_B = 100(11.8\mu) = \underline{1.18mA} = I_{CQ}$

$v_{CE} = -5k i_C + 20 - 1k(i_B + i_C) = -5k i_C + 20 - 1k(i_B + 100i_B)$
 $= -5k(1.18m) + 20 - 1k(101)(11.8\mu)$
 $= -5.9 + 20 - 1.19$
 $= \underline{12.9V} = V_{CEQ}$

Since $i_B > 0A$ and $v_{CE} > 0.2V$, then active-region operation is confirmed.

7.11



(a) By KVL,

$2 = 20k i_B + v_{BE} + 100(i_B + i_C)$ For active region, $v_{BE} = 0.7V$, $i_C = \beta i_B$

$2 - 0.7 = 20k i_B + 100(i_B + 100i_B) = 20k i_B + 10100 i_B = 30.1k i_B$

$i_B = \frac{1.3}{30.1k} = \underline{43.2\mu A}$

(b) $i_C = 100 i_B = 100(43.2\mu) = \underline{4.32mA} > 0$

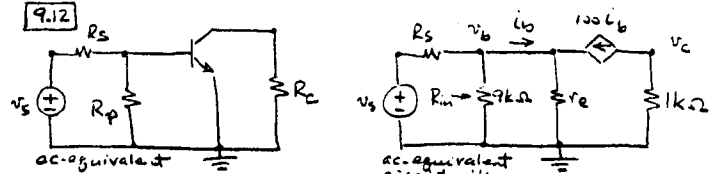
(c) $v_{CE} = -1k i_C + 6 = 100(i_B + i_C)$

$= -1k(4.32m) + 6 = 100(43.2\mu + 4.32m)$

$= -4.32 + 6 = 0.436$

$v_{CE} = \underline{1.2V} > 0.2V$

7.9.12



$R_p = R_1 // R_2 = 90k // 10k$

$R_p = \frac{(90k)(10k)}{90k + 10k} = 9k\Omega$

$I_{CQ} = 10mA$

(a) $r_m = \frac{I_{CQ}}{0.026} = \frac{10m}{26m} = \underline{385\Omega}$

(b) $r_e = \frac{0.026}{I_{CQ}} = \frac{26m}{10m} = \underline{2.6\Omega}$

(c) $v_b = r_e(i_b + 100i_b) = 2.6(101)i_b \Rightarrow R_b = \frac{v_b}{i_b} = 2.6(101)$
 $R_b = 263\Omega$

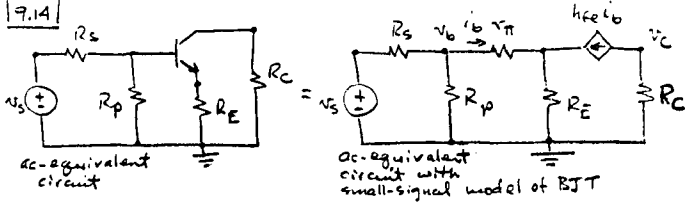
$R_{in} = R_p // R_b = 9k // 263 = \frac{(9k)(263)}{9k + 263} = \underline{256\Omega}$

(d) $v_c = -1k(100i_b) = -100k i_b$

$v_b = 2.6(101)i_b$

$\therefore A_v = \frac{v_c}{v_b} = \frac{-100k}{2.6(101)} = \underline{-381}$

9.14



(a) By KVL, $v_b = r_{\pi} i_b + R_E (i_b + h_{fe} i_b) = [r_{\pi} + R_E (1 + h_{fe})] i_b$

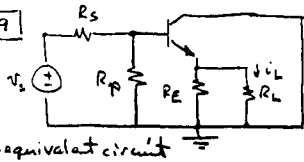
$$\therefore R_b = \frac{v_b}{i_b} = \underline{\underline{r_{\pi} + (1 + h_{fe}) R_E}}$$

(b) $v_c = -R_C h_{fe} i_b$

$$v_b = [r_{\pi} + R_E (1 + h_{fe})] i_b$$

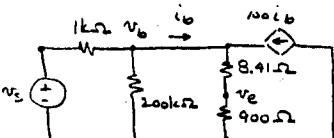
$$\therefore A_v = \frac{v_c}{v_b} = \underline{\underline{-\frac{R_C h_{fe}}{r_{\pi} + R_E (1 + h_{fe})}}}$$

9.19



ac-equivalent circuit

$I_{CQ} = 3.09 \text{ mA}$
 $r_e = \frac{0.026}{I_{CQ}} = \frac{26 \text{ mV}}{3.09 \text{ mA}} = 8.41 \Omega$
 $r_p = R_1 \parallel R_2 = 400 \text{ k} \parallel 400 \text{ k} = 200 \text{ k} \Omega$
 $R_T = R_E \parallel R_L = 1 \text{ k} \parallel 9 \text{ k}$
 $R_T = \frac{(1 \text{ k})(9 \text{ k})}{1 \text{ k} + 9 \text{ k}} = 900 \Omega$



ac-equivalent circuit with small-signal BJT model

(a) $v_b = (8.41 + 900)(i_b + 100 i_b) = 91.7 \text{ k} i_b \Rightarrow R_b = \frac{v_b}{i_b} = 91.7 \text{ k} \Omega$

$$v_e = 900(i_b + 100 i_b) = 90.9 \text{ k} i_b$$

$$\therefore A_v = \frac{v_e}{v_b} = \frac{90.9}{91.7} = \underline{\underline{0.991}}$$

(b) $r_{in} = R_p \parallel R_b = 200 \text{ k} \parallel 91.7 \text{ k} = \frac{(200 \text{ k})(91.7 \text{ k})}{200 \text{ k} + 91.7 \text{ k}} = \underline{\underline{62.9 \text{ k} \Omega}}$

(c) By current division, $i_L = \frac{R_E}{R_E + R_L} (101 i_b) = \frac{1 \text{ k}}{1 \text{ k} + 9 \text{ k}} (101 i_b) = 10.1 i_b$

$$\therefore A_i = \frac{i_L}{i_b} = \underline{\underline{10.1}}$$